## **DISCRETE SEMICONDUCTORS**

## DATA SHEET



# **BAL74**High-speed diode

Product data sheet Supersedes data of 1999 May 26 2003 Dec 17

勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-34970699 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw



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## **High-speed diode**

**FEATURES** 

- · Small plastic SMD package
- · High switching speed: max. 4 ns
- Continuous reverse voltage: max. 50 V
- Repetitive peak reverse voltage: max. 50 V
- Repetitive peak forward current: max. 500 mA.

#### **APPLICATIONS**

· High-speed switching in e.g. surface mounted circuits.

#### **DESCRIPTION**

The BAL74 is a high-speed switching diode fabricated in planar technology, and encapsulated in the small SOT23 plastic SMD package.

#### MARKING

TYPE NUMBER	MARKING CODE(1)		
BAL74	JC*		

#### Note

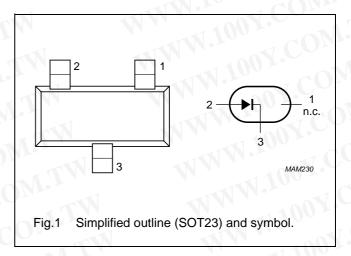
\* = p : Made in Hong Kong.

\* = t : Made in Malaysia.

\* = W : Made in China.

#### **PINNING**

PIN	DESCRIPTION	
1	not connected	
2	anode	
3	cathode	



#### ORDERING INFORMATION

TYPE NUMBER	W	PACKAGE	
TYPE NUMBER	NAME	DESCRIPTION	VERSION
BAL74		plastic surface mounted package; 3 leads	SOT23

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#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RRM}$	repetitive peak reverse voltage	1.11	17 -	50	٧
$V_R$	continuous reverse voltage		-n\$1	50	V
I <sub>F</sub>	continuous forward current	see Fig.2; note 1	no.	215	mA
I <sub>FRM</sub>	repetitive peak forward current		-00	500	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; T <sub>j</sub> = 25 °C prior to surge; see Fig.4	Too	V.C	ON
	1 100 E	$t_p = 1 \mu s$	1-7n	4	Α
	WWW. COV.	$t_p = 1 \text{ ms}$	-	1	Α
	100	$t_p = 1 \text{ s}$	1.1	0.5	A
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; note 1	-	250	mW
T <sub>stg</sub>	storage temperature	COM	-65	+150	°C
Ţ	junction temperature	J. T. T. W.	-	150	°C

#### Note

1. Device mounted on an FR4 printed-circuit board.

#### **ELECTRICAL CHARACTERISTICS**

 $T_j = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V <sub>F</sub>	forward voltage	see Fig.3		x/ 1
	· VIVI	I <sub>F</sub> = 1 mA	715	mV
	V.I.	I <sub>F</sub> = 10 mA	855	mV
	TIN TIN	I <sub>F</sub> = 50 mA	1	V
	W. I.	I <sub>F</sub> = 150 mA	1.25	V
I <sub>R</sub>	reverse current	see Fig.5		
	OWIT	V <sub>R</sub> = 50 V	0.1	μΑ
	UT IN	V <sub>R</sub> = 50 V; T <sub>j</sub> = 150 °C	100	μΑ
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 0; see Fig.6	2	pF
t <sub>rr</sub>	reverse recovery time	when switched from $I_F$ = 10 mA to $I_R$ = 10 mA; $R_L$ = 100 $\Omega$ ; measured at $I_R$ = 1 mA; see Fig.7	4	ns
V <sub>fr</sub>	forward recovery voltage	when switched from $I_F = 10$ mA; $t_r = 20$ ns; see Fig.8	1.75	V

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-tp)</sub>	thermal resistance from junction to tie-point	COM	330	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	note 1	500	K/W

#### Note

1. Device mounted on an FR4 printed-circuit board.

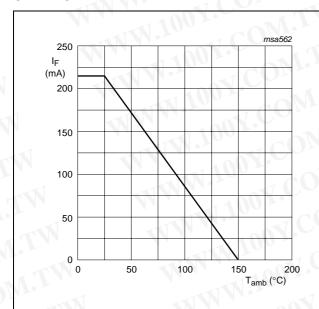
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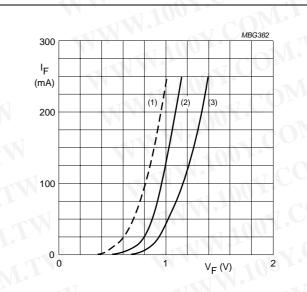
## High-speed diode

#### **GRAPHICAL DATA**



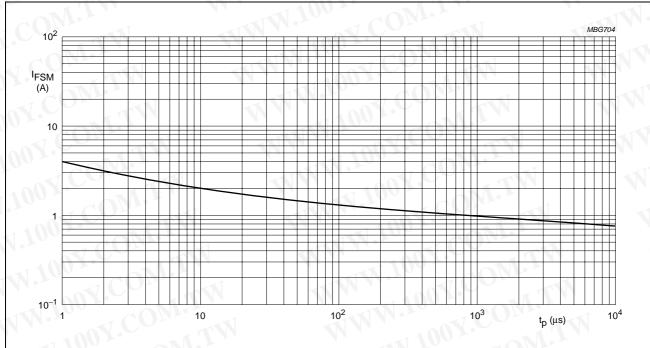
Device mounted on an FR4 printed-circuit board.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



- (1)  $T_j = 150 \,^{\circ}\text{C}$ ; typical values.
- (2)  $T_j = 25$  °C; typical values.
- (3) T<sub>j</sub> = 25 °C; maximum values.

Fig.3 Forward current as a function of forward voltage.



Based on square wave currents; T<sub>i</sub> = 25 °C prior to surge.

Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

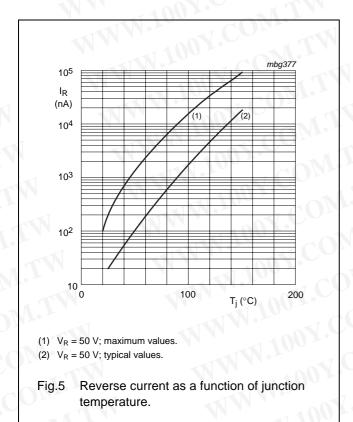
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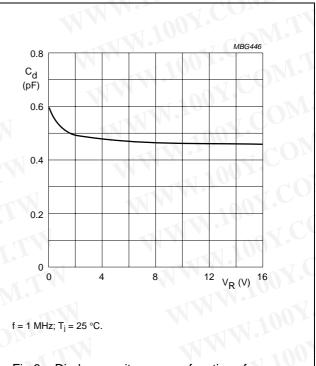


Fig.6 Diode capacitance as a function of reverse voltage; typical values.

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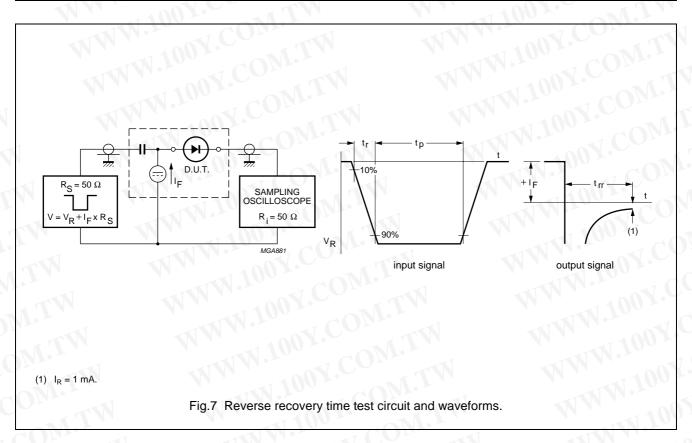
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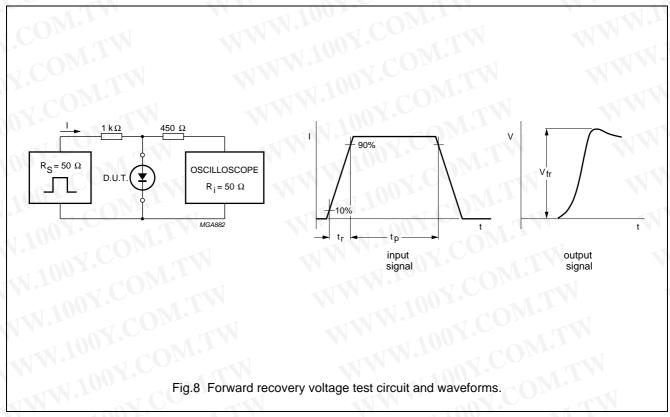
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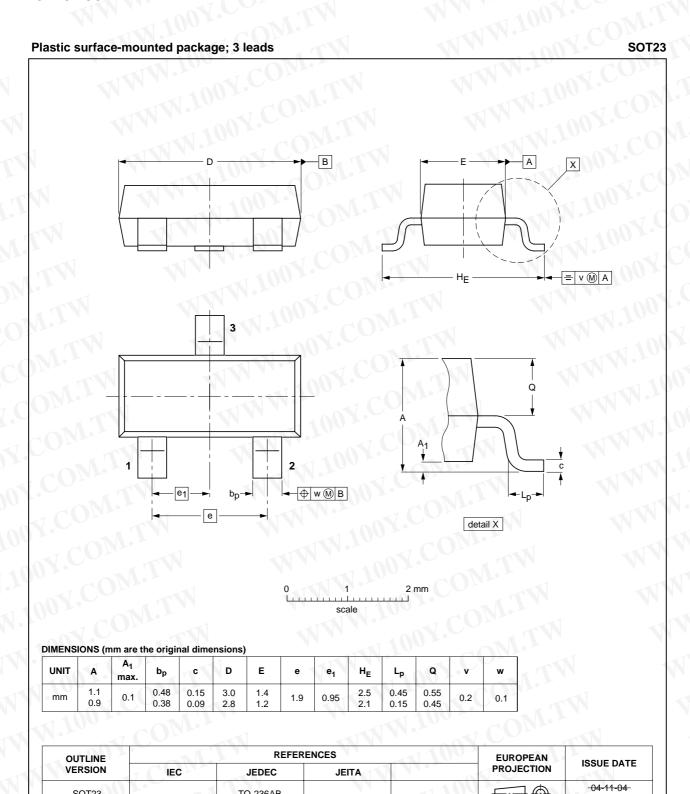
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## High-speed diode

#### **PACKAGE OUTLINE**



TO-236AB

SOT23

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## High-speed diode

#### **DATA SHEET STATUS**

DOCUMENT STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### **Notes**

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#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

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